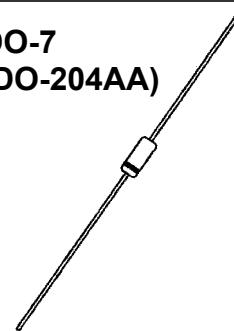


**Microsemi**

SCOTTSDALE DIVISION

1N941 thru 1N946B-1**11.7 Volt Temperature Compensated Zener
Reference Diodes****DESCRIPTION**

The popular 1N941 thru 1N946B series of Zero-TC Reference Diodes provides a selection of 11.7 V nominal voltages and temperature coefficients to as low as 0.0002%/°C for minimal voltage change with temperature when operated at 7.5 mA. These glass axial-leaded DO-7 reference diodes are also available in JAN, JANTX, and JANTXV military qualifications. Microsemi also offers numerous other Zener Reference Diode products for a variety of other voltages from 6.2 V to 200 V.

APPEARANCE**DO-7
(DO-204AA)**

IMPORTANT: For the most current data, consult *MICROSEMI*'s website: <http://www.microsemi.com>

FEATURES

- JEDEC registered 1N941 thru 1N946B series
- Standard reference voltage of 11.7 V +/- 5% with tighter tolerances also available
- 1N941B, 942B, 943B, 944B, 945B also have military qualification to MIL-PRF-19500/157 up to the JANTXV level by adding JAN, JANTX, or JANTXV prefixes to part numbers as well as "-1" suffix, e.g. JANTX1N944B-1, etc.
- Internal metallurgical bonds
- JANS Equivalent available via SCD
- Radiation Hardened devices available by changing "1N" prefix to "RH", e.g. RH944B, RH945B, etc. Also consult factory for "RH" data sheet brochure

APPLICATIONS / BENEFITS

- Provides minimal voltage changes over a broad temperature range
- For instrumentation and other circuit designs requiring a stable voltage reference
- Maximum temperature coefficient selections available from 0.01%/°C to 0.0002%/°C
- Tight reference voltage tolerances available at 11.7 V nominal values by adding the tolerance 1%, 2%, 3%, etc. after the part number for further identification e.g. 1N944B-2%, 1N945A-1%, 1N944B-1-1%, etc.
- Flexible axial-lead mounting terminals
- Nonsensitive to ESD per MIL-STD-750 Method 1020

MAXIMUM RATINGS

- Operating & Storage Temperature: -65°C to +175°C
- DC Power Dissipation: 500 mW @ $T_L = 25^\circ\text{C}$ and maximum current I_{ZM} of 39 mA. NOTE: For optimum voltage-temperature stability, $I_Z = 7.5$ mA (less than 95 mW in dissipated power)
- Solder temperatures: 260 °C for 10 s (maximum)

MECHANICAL AND PACKAGING

- CASE: Hermetically sealed glass case with DO-7 (DO-204AA) package
- TERMINALS: Tin-lead plated and solderable per MIL-STD-750, Method 2026
- MARKING: Part number and cathode band
- POLARITY: Reference diode to be operated with the banded end positive with respect to the opposite end
- TAPE & REEL option: Standard per EIA-296 (add "TR" suffix to part number)
- WEIGHT: 0.2 grams.
- See package dimensions on last page

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Reference Diodes*****ELECTRICAL CHARACTERISTICS @ 25°C, unless otherwise specified**

JEDEC TYPE NUMBER (Note 1, 5 & 6)	ZENER VOLTAGE V_z @ I_{zT} (Note 4)	ZENER TEST CURRENT I_{zT}	MAXIMUM ZENER IMPEDANCE (Note 2) Z_{zT} @ I_{zT}	MAXIMUM REVERSE CURRENT I_R @ 8 V	VOLTAGE TEMPERATURE STABILITY (Note 3 & 4) ΔV_{zT} MAXIMUM	TEMPERATURE RANGE	EFFECTIVE TEMPERATURE COEFFICIENT α_{Vz}
	VOLTS	mA	OHMS	μ A	mV	°C	%/°C
1N941	11.12-12.28	7.5	30	15	88	0 to +75	0.01
1N941A	11.12-12.28	7.5	30	15	181	-55 to +100	0.01
1N941B	11.12-12.28	7.5	30	15	239	-55 to +150	0.01
1N942	11.12-12.28	7.5	30	15	44	0 to +75	0.005
1N942A	11.12-12.28	7.5	30	15	90	-55 to +100	0.005
1N942B	11.12-12.28	7.5	30	15	120	-55 to +150	0.005
1N943	11.12-12.28	7.5	30	15	18	0 to +75	0.002
1N943A	11.12-12.28	7.5	30	15	36	-55 to +100	0.002
1N943B	11.12-12.28	7.5	30	15	47	-55 to +150	0.002
1N944	11.12-12.28	7.5	30	15	9	0 to +75	0.001
1N944A	11.12-12.28	7.5	30	15	18	-55 to +100	0.001
1N944B	11.12-12.28	7.5	30	15	24	-55 to +150	0.001
1N945	11.12-12.28	7.5	30	15	4	0 to +75	0.0005
1N945A	11.12-12.28	7.5	30	15	9	-55 to +100	0.0005
1N945B	11.12-12.28	7.5	30	15	12	-55 to +150	0.0005
1N946	11.12-12.28	7.5	30	15	1.8	0 to +75	0.0002
1N946A	11.12-12.28	7.5	30	15	3.6	-55 to +100	0.0002
1N946B	11.12-12.28	7.5	30	15	4.7	-55 to +150	0.0002

*JEDEC Registered Data.

NOTES:

1. For tighter voltages tolerances, add a hyphenated suffix to the part number for desired tolerance at the end of the part number, e.g. 1N944B-2%, 1N945B-1%, 1N944B-1-1%, etc.
2. Measured by superimposing 0.75 mA ac rms on 7.5 mA dc @ 25°C.
3. The maximum allowable change observed over the entire temperature range i.e., the diode voltage will not exceed the specified mV change at any discrete temperature between the established limits.
4. Voltage measurements to be performed 15 seconds after application of dc current.
5. The 1N941B, 1N942B, 1N943B, 1N944B, 1N945B also have military qualification to MIL-PRF-19500/157 up to the JANTXV level by adding JAN, JANTX, or JANTXV prefixes to part numbers as well as “-1” suffix, e.g. JANTX1N944B-1, JANTXV1N945B-1, etc.
6. Designate Radiation Hardened devices with “RH” prefix instead of “1N”, i.e. RH944B instead of 1N944B.

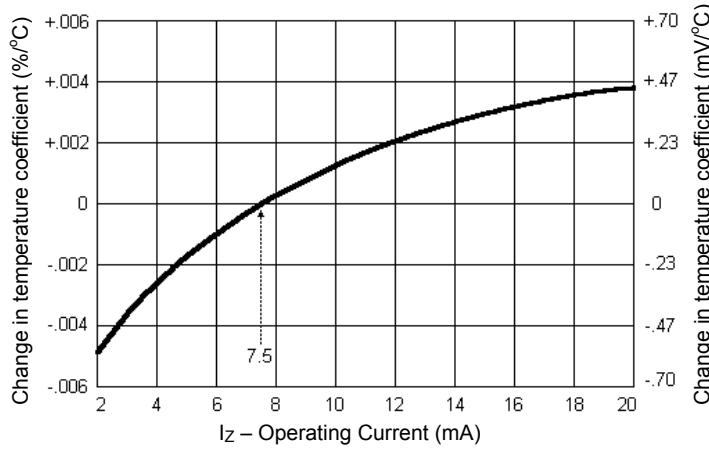
GRAPHS

FIGURE 1
**TYPICAL CHANGE OF TEMPERATURE COEFFICIENT
WITH CHANGE IN OPERATING CURRENT.**

The curve shown in Figure 1 is typical of the diode series and greatly simplifies the estimation of the Temperature Coefficient (TC) when the diode is operated at currents other than 7.5mA.

EXAMPLE: A diode in this series is operated at a current of 7.5mA and has specified Temperature Coefficient (TC) limits of +/- 0.002%°C. To obtain the typical Temperature Coefficient limits for this same diode operated at a current of 6.0mA, the new TC limits (%/°C) can be estimated using the graph in FIGURE 1.

At a test current of 6.0mA the change in Temperature Coefficient (TC) is approximately -0.0009%°C. The algebraic sum of +/- 0.002%°C and -0.0009%°C gives the new estimated limits of +0.0011%°C and -0.0029%°C.



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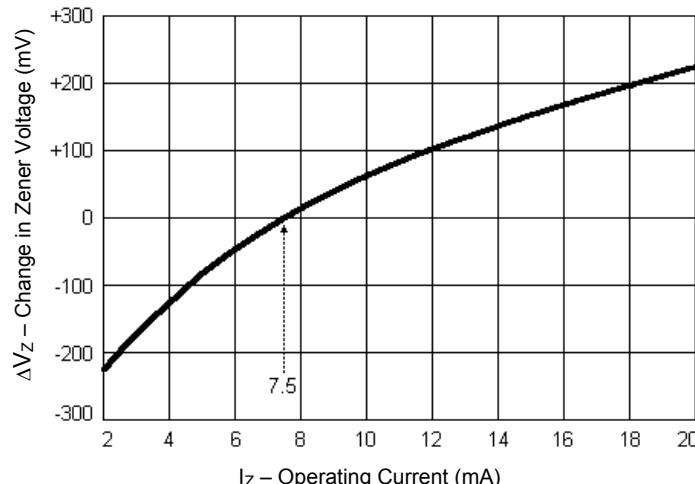


FIGURE 2

**TYPICAL CHANGE OF ZENER VOLTAGE
WITH CHANGE IN OPERATING CURRENT.**

This curve in Figure 2 illustrates the change of diode voltage arising from the effect of impedance. It is in effect, an exploded view of the zener operating region of the I-V characteristic.

In conjunction with Figure 1, this curve can be used to estimate total voltage regulation under conditions of both varying temperature and current.

DIMENSIONS

